



DXTN07100BP5

100V NPN MEDIUM POWER LOW SATURATION TRANSISTOR
PowerDI[®]5

Features

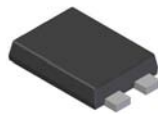
- 43% smaller than SOT223; 60% smaller than TO252
- Maximum height just 1.1mm
- Rated up to 3.2W
- $V_{CE0} = 100V$
- $I_C = 2A$; $I_{CM} = 6A$
- Low Saturation, high gain transistor,
- **Lead, Halogen and Antimony Free, RoHS Compliant (Note 1)**
- **“Green” Device (Note 2)**

Features

- Regular circuits

Mechanical Data

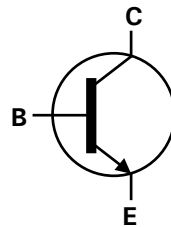
- Case: PowerDI[®]5
- Case Material: Molded Plastic, “Green” Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish – Matte Tin annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208 [Ⓒ]3
- Weight: 0.093 grams (approximate)



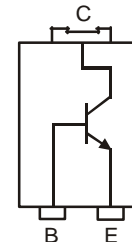
Top View



Bottom View



Device Schematic



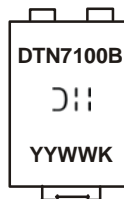
Pin-out diagram

Ordering Information (Note 3)

Part Number	Case	Packaging
DXTN07100BP5-13	PowerDI [®] 5	5000/Tape & Reel

- Notes:
1. No purposefully added lead. Halogen and Antimony Free.
 2. Diodes Inc's “Green” Policy can be found on our website at <http://www.diodes.com>
 3. For packaging details, go to our website at <http://www.diodes.com/datasheets/ap02007.pdf>.

Marking Information



- DTN7100B = Product Type Marking Code
- Ⓜ = Manufacturer's Code Marking
- K = Factory Designator
- YYWW = Date Code Marking
- YY = Last Two Digits of Year (ex: 09 for 2009)
- WW = Week code (01 to 53)

PowerDI is a registered trademark of Diodes Incorporated.

Maximum Ratings @ $T_A = 25^\circ\text{C}$ unless otherwise specified

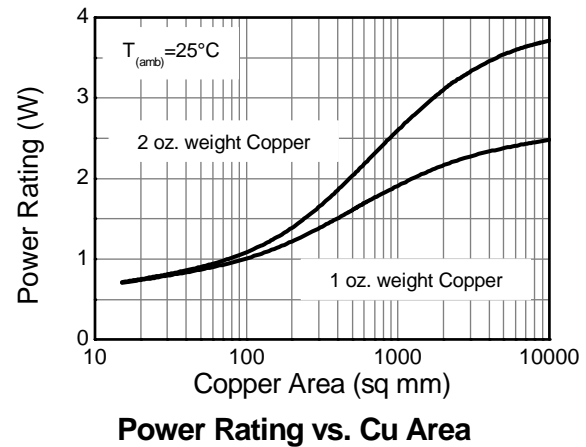
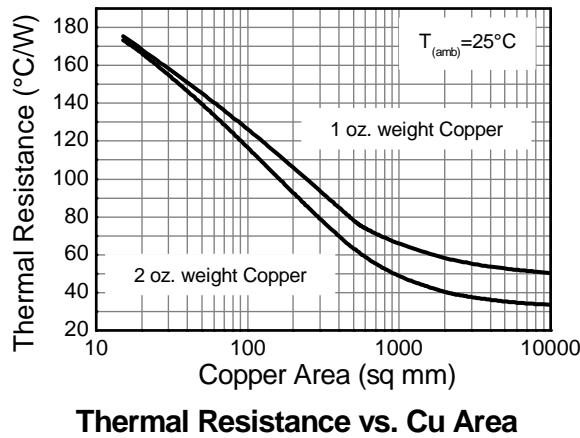
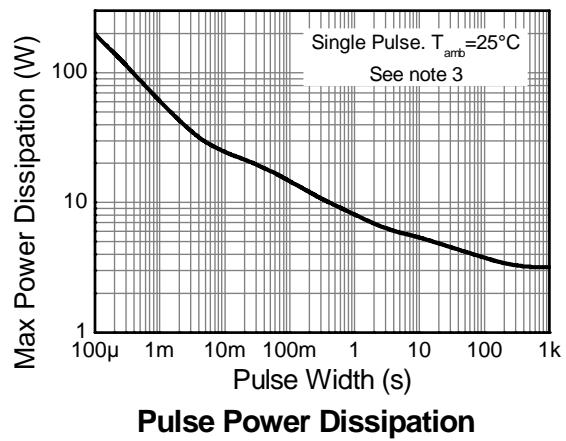
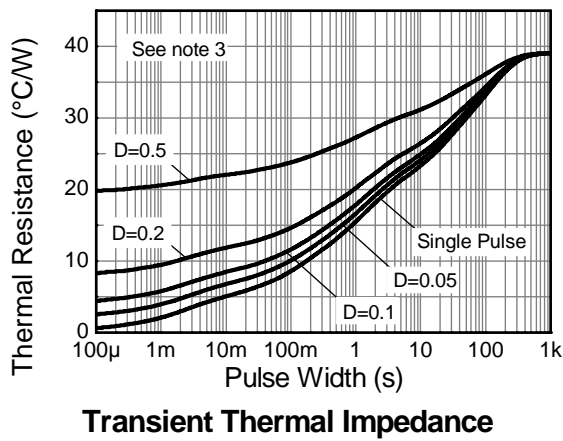
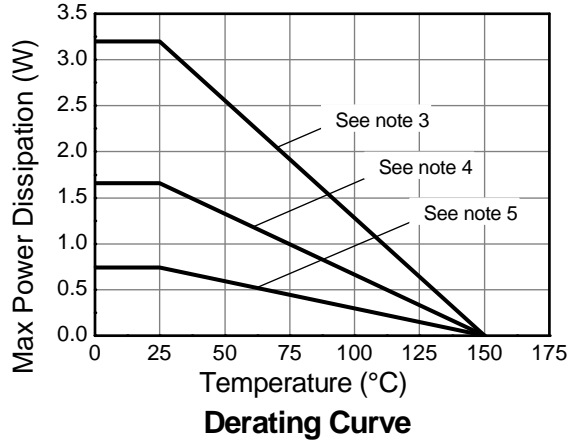
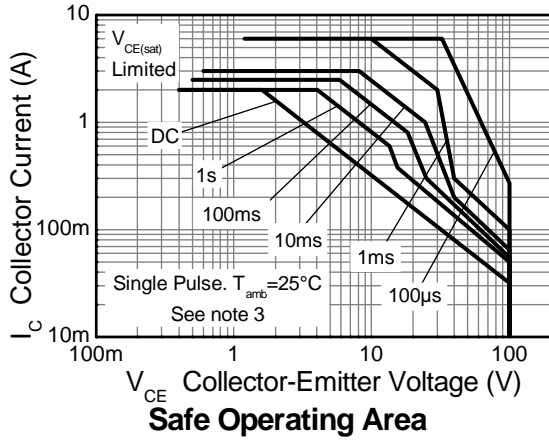
Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CB0}	120	V
Collector-Emitter Voltage	V_{CEO}	100	V
Emitter-Base Voltage	V_{EBO}	5	V
Continuous Collector Current	I_C	2	A
Peak Pulse Current	I_{CM}	6	A

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation @ $T_A = 25^\circ\text{C}$ (Note 4)	P_D	3.2	W
Thermal Resistance, Junction to Ambient Air (Note 4) @ $T_A = 25^\circ\text{C}$	$R_{\theta JA}$	39	$^\circ\text{C/W}$
Power Dissipation @ $T_A = 25^\circ\text{C}$ (Note 5)	P_D	1.7	W
Thermal Resistance, Junction to Ambient Air (Note 5) @ $T_A = 25^\circ\text{C}$	$R_{\theta JA}$	75	$^\circ\text{C/W}$
Power Dissipation @ $T_A = 25^\circ\text{C}$ (Note 6)	P_D	0.74	W
Thermal Resistance, Junction to Ambient Air (Note 6) @ $T_A = 25^\circ\text{C}$	$R_{\theta JA}$	169	$^\circ\text{C/W}$
Thermal Resistance, Junction to Collector Terminal	$R_{\theta JT}$	8.9	$^\circ\text{C/W}$
Operating and Storage Temperature Range	T_J, T_{STG}	-55 to +150	$^\circ\text{C}$

- Notes:
4. Device mounted on FR-4 PCB, single sided 2 oz. copper, collector pad dimensions 50mm x 50mm.
 5. Device mounted on FR-4 PCB, single sided 1 oz. copper, collector pad dimensions 50mm x 50mm.
 6. Device mounted on FR-4 PCB, single sided 1 oz. copper, minimum recommended pad layout.

DXTN07100BP5

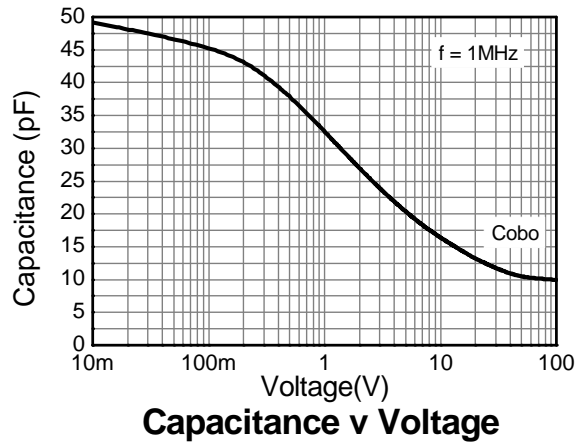
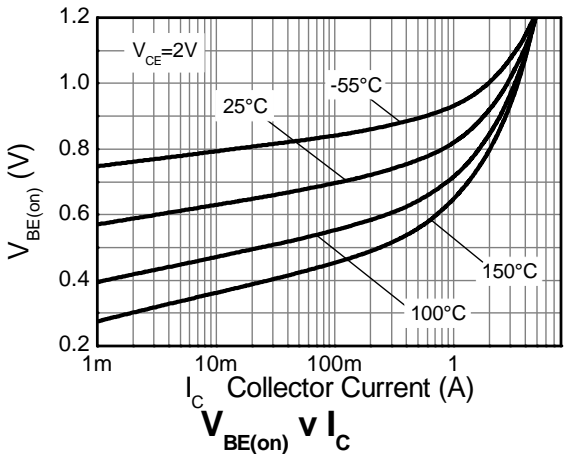
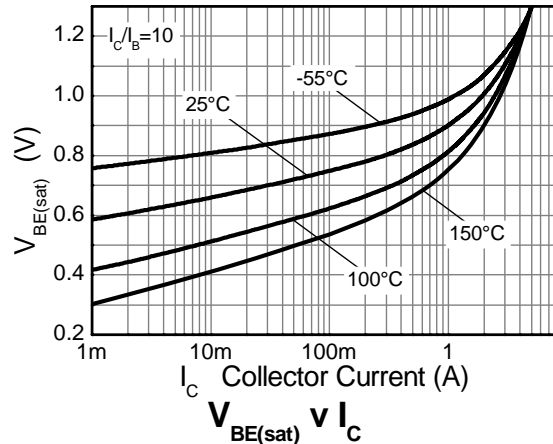
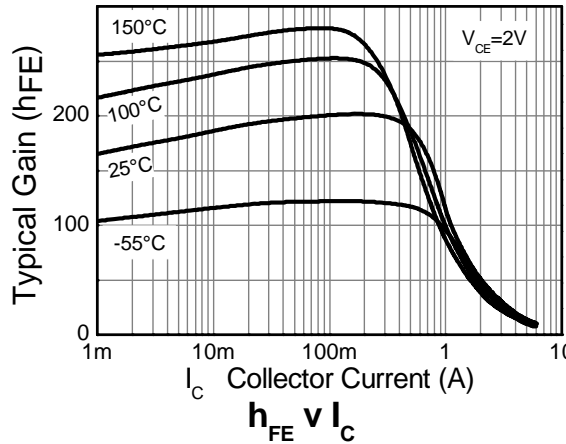
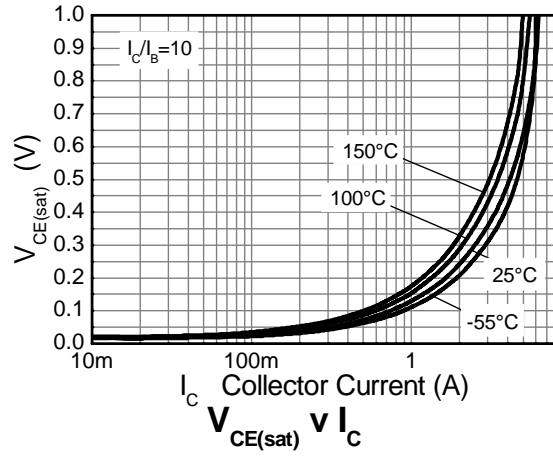
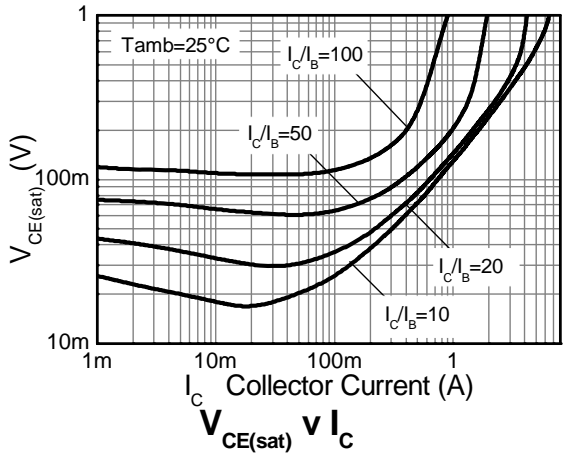


Electrical Characteristics @T_A = 25°C unless otherwise specified

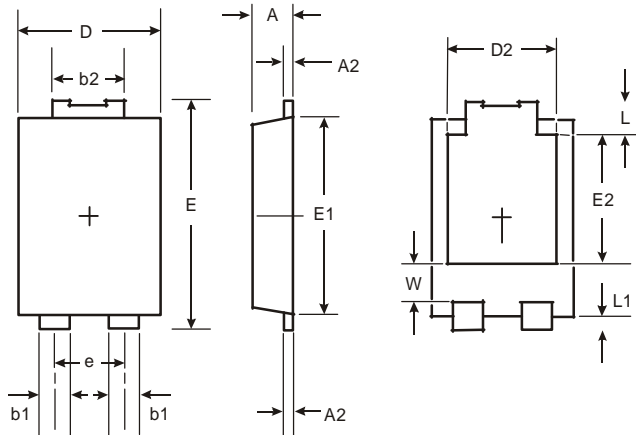
Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	V _{(BR)CBO}	120	—	—	V	I _C = 100μA
Collector-Emitter Breakdown Voltage (Note 7)	V _{(BR)CEO}	100	—	—	V	I _C = 10mA
Emitter-Base Breakdown Voltage	V _{(BR)EBO}	5	—	—	V	I _E = 100μA
Collector Cutoff Current	I _{CBO}	—	—	0.1 10	μA	V _{CB} = 100V V _{CB} = 100V, T _{amb} = 100 °C
Emitter Cutoff Current	I _{EBO}	—	—	0.1	μA	V _{EB} = 4V
Collector-Emitter Saturation Voltage (Note 7)	V _{CE(sat)}	—	0.13 0.23	0.3 0.5	V	I _C = 1A, I _B = 100mA I _C = 2A, I _B = 200mA
Base-Emitter Saturation Voltage (Note 7)	V _{BE(sat)}	—	0.9	1.25	V	I _C = 1A, I _B = 100mA
Base-Emitter Turn-On Voltage (Note 7)	V _{BE(on)}	—	0.8	1.00	V	I _C = 1A, V _{CE} = 2V
DC Current Gain (Note 7)	h _{FE}	70 100 55 25	200 200 110 55	— 300 — —	—	I _C = 50mA, V _{CE} = 2V I _C = 500mA, V _{CE} = 2V I _C = 1A, V _{CE} = 2V I _C = 2A, V _{CE} = 2V
Transition Frequency	f _T	140	175	—	MHz	I _C = 100mA, V _{CE} = 5V f = 100MHz
Output Capacitance	C _{obo}	—	—	30	pF	V _{CB} = 10A, f = 1MHz
Switching Times	t _{on} t _{off}	— —	80 1200	— —	ns ns	I _C = 500mA, V _{CC} = 10V, I _{B1} = I _{B2} = 50mA

Notes: 7. Pulse Test: Pulse width ≤300μs. Duty cycle ≤2.0%.

Typical Characteristic

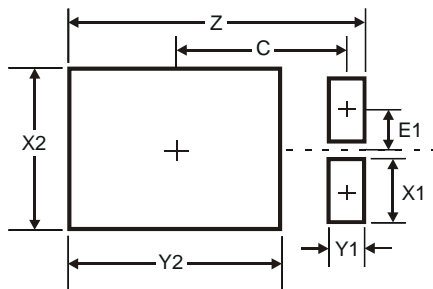


Package Outline Dimensions



PowerDI ^{®5}		
Dim	Min	Max
A	1.05	1.15
A2	0.33	0.43
b1	0.80	0.99
b2	1.70	1.88
D	3.90	4.05
D2	3.054 Typ	
E	6.40	6.60
e	1.84 Typ	
E1	5.30	5.45
E2	3.549 Typ	
L	0.75	0.95
L1	0.50	0.65
W	1.10	1.41
All Dimensions in mm		

Suggested Pad Layout



Dimensions	Value (in mm)
Z	6.6
X1	1.4
X2	3.6
Y1	0.8
Y2	4.7
C	3.87
E1	0.9

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- Техническая поддержка проекта;
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Как с нами связаться

Телефон: 8 (812) 309 58 32 (многоканальный)

Факс: 8 (812) 320-02-42

Электронная почта: org@eplast1.ru

Адрес: 198099, г. Санкт-Петербург, ул. Калинина, дом 2, корпус 4, литера А.